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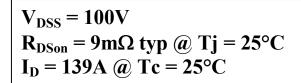


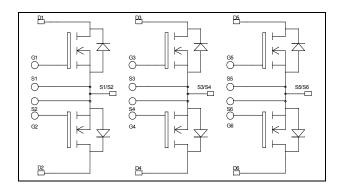






Triple dual common source MOSFET Power Module





Application

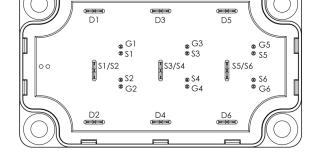
- AC Switches
- Switched Mode Power Supplies
- Uninterruptible Power Supplies

Features

- Power MOS V[®] MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- High level of integration



- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Very low (12mm) profile
- Each leg can be easily paralleled to achieve a dual common source configuration of three times the current capability
- RoHS Compliant



Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		100	V
т	Continuous Drain Current	$T_c = 25$ °C	139	
I_D		$T_c = 80$ °C	100	A
I_{DM}	Pulsed Drain current		430	
V_{GS}	Gate - Source Voltage		±30	V
R_{DSon}	Drain - Source ON Resistance		10	mΩ
P_{D}	Maximum Power Dissipation $T_c = 25^{\circ}C$		390	W
I_{AR}	Avalanche current (repetitive and non repetitive)		100	Α
E_{AR}	Repetitive Avalanche Energy		50	ma I
E_{AS}	Single Pulse Avalanche Energy		3000	mJ

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 100V$	$T_j = 25^{\circ}C$			100	μА
		$V_{GS} = 0V, V_{DS} = 80V$	$T_j = 125$ °C			500	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 69.5A$			9	10	mΩ
V _{GS(th)}	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 2.5 \text{mA}$		2		4	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$				±100	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		9875		
C_{oss}	Output Capacitance	$V_{\rm DS} = 25V$		3940		pF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		1470		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		350		
Q_{gs}	Gate – Source Charge	$V_{Bus} = 50V$		60		nC
$Q_{gd} \\$	Gate – Drain Charge	$I_{D} = 139A$		180		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		35		
$T_{\rm r}$	Rise Time	$V_{GS} = 15V$		70		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 66V$ $I_{\text{D}} = 139A$		95		ns
T_{f}	Fall Time	$R_G = 5\Omega$		125		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		552		
E_{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 139A, R_G = 5\Omega$		604		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		608		Ţ
E _{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 139A, R_G = 5\Omega$		641		μJ

Source - Drain diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
Ţ	Continuous Source current		$Tc = 25^{\circ}C$			139	Α
I_{S}	(Body diode)		$Tc = 80^{\circ}C$			100	A
V_{SD}	Diode Forward Voltage	$V_{GS} = 0V, I_S = -139A$				1.3	V
dv/dt	Peak Diode Recovery •					5	V/ns
t_{rr}	Reverse Recovery Time	$I_S = -139A$	$T_j = 25^{\circ}C$		270		ns
Q_{rr}	Reverse Recovery Charge	$V_R = 66V$ $di_S/dt = 100A/\mu s$	$T_j = 25$ °C		2.9		μC

• dv/dt numbers reflect the limitations of the circuit rather than the device itself.

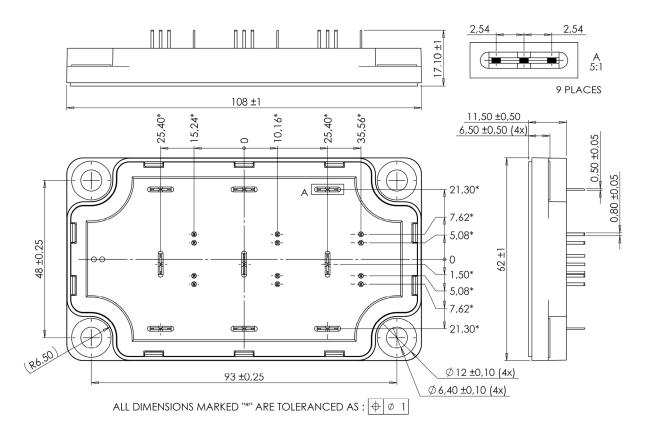
 $I_S \leq \text{- }139A \qquad \text{di/dt} \leq 700A/\mu s \qquad V_R \leq V_{DSS} \qquad T_j \leq 150^{\circ}C$



Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance					0.32	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
Wt	Package Weight		•			250	g

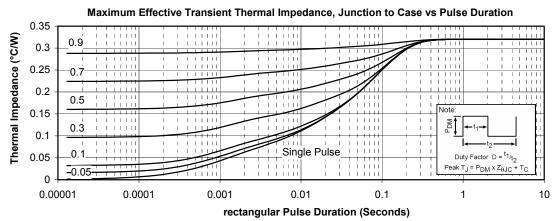
SP6-P Package outline (dimensions in mm)

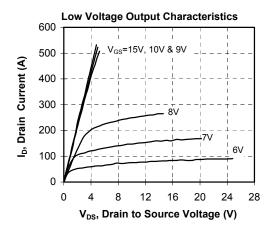


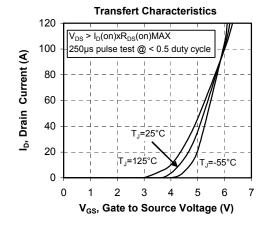
See application note 1902 - Mounting Instructions for SP6-P (12mm) Power Modules on www.microsemi.com

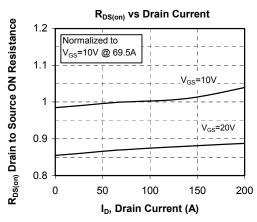


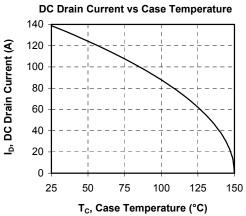
Typical Performance Curve





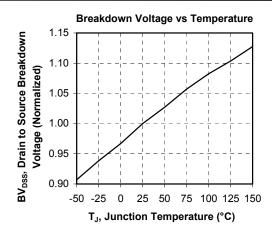


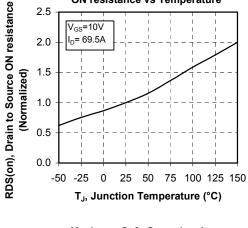


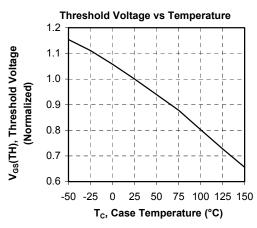


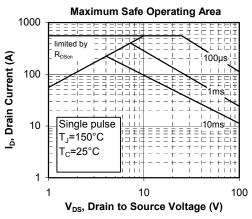


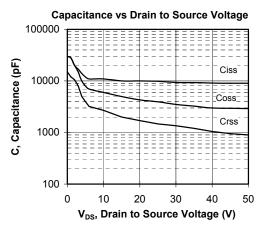
ON resistance vs Temperature

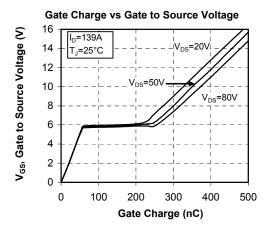






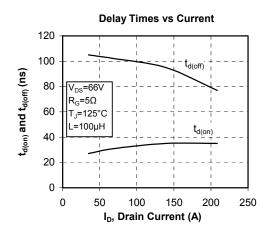


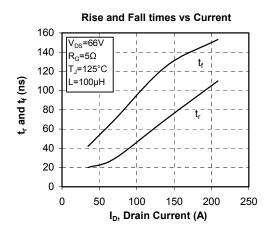


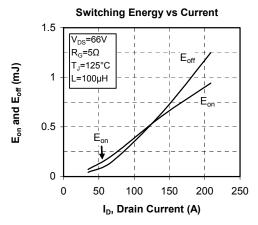


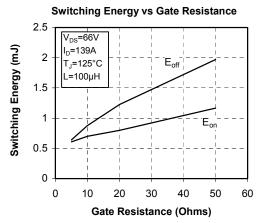
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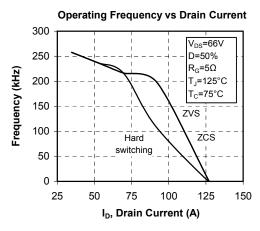


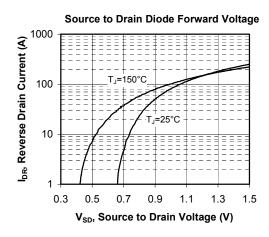












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